

# MMBT2222LT1, MMBT2222ALT1

MMBT2222ALT1 is a Preferred Device

## General Purpose Transistors

### NPN Silicon

#### Features

- Pb-Free Packages are Available

#### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector - Emitter Voltage MMBT2222LT1 MMBT2222ALT1	$V_{CE0}$	30 40	Vdc
Collector - Base Voltage MMBT2222LT1 MMBT2222ALT1	$V_{CBO}$	60 75	Vdc
Emitter - Base Voltage MMBT2222LT1 MMBT2222ALT1	$V_{EBO}$	5.0 6.0	Vdc
Collector Current - Continuous	$I_C$	600	mAdc
Collector Current - Peak (Note 3)	$I_{CM}$	1100	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	225 1.8	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	$^\circ\text{C}/\text{W}$
Total Device Dissipation Alumina Substrate (Note 2) $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	300 2.4	mW mW/ $^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	$^\circ\text{C}/\text{W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

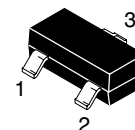
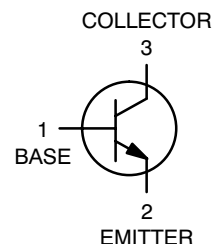
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.
- Reference SOA curve.



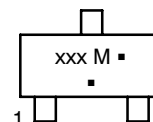
ON Semiconductor®

<http://onsemi.com>



SOT-23  
CASE 318  
STYLE 6

#### MARKING DIAGRAM



xxx = 1P or M1B  
M = Date Code\*  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

# MMBT2222LT1, MMBT2222ALT1

## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>OFF CHARACTERISTICS</b>				
Collector - Emitter Breakdown Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0) MMBT2222A	MMBT2222 V <sub>(BR)CEO</sub>	30 40	- -	Vdc
Collector - Base Breakdown Voltage (I <sub>C</sub> = 10 μAdc, I <sub>E</sub> = 0) MMBT2222A	MMBT2222 V <sub>(BR)CBO</sub>	60 75	- -	Vdc
Emitter - Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0) MMBT2222A	MMBT2222 V <sub>(BR)EBO</sub>	5.0 6.0	- -	Vdc
Collector Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)	MMBT2222A I <sub>CEX</sub>	-	10	nAdc
Collector Cutoff Current (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0) (V <sub>CB</sub> = 50 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 125°C) (V <sub>CB</sub> = 60 Vdc, I <sub>E</sub> = 0, T <sub>A</sub> = 125°C)	MMBT2222 MMBT2222A MMBT2222 MMBT2222A I <sub>CBO</sub>	- - - -	0.01 0.01 10 10	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = 3.0 Vdc, I <sub>C</sub> = 0)	MMBT2222A I <sub>EBO</sub>	-	100	nAdc
Base Cutoff Current (V <sub>CE</sub> = 60 Vdc, V <sub>EB(off)</sub> = 3.0 Vdc)	MMBT2222A I <sub>BL</sub>	-	20	nAdc
<b>ON CHARACTERISTICS</b>				
DC Current Gain (I <sub>C</sub> = 0.1 mAdc, V <sub>CE</sub> = 10 Vdc) (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, T <sub>A</sub> = -55°C) (I <sub>C</sub> = 150 mAdc, V <sub>CE</sub> = 10 Vdc) (Note 4) (I <sub>C</sub> = 150 mAdc, V <sub>CE</sub> = 1.0 Vdc) (Note 4) (I <sub>C</sub> = 500 mAdc, V <sub>CE</sub> = 10 Vdc) (Note 4)	MMBT2222A only MMBT2222 MMBT2222A h <sub>FE</sub>	35 50 75 35 100 50 30 40	- - - - 300 - - -	-
Collector - Emitter Saturation Voltage (Note 4) (I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)  (I <sub>C</sub> = 500 mAdc, I <sub>B</sub> = 50 mAdc)	MMBT2222 MMBT2222A MMBT2222 MMBT2222A V <sub>CE(sat)</sub>	- - - -	0.4 0.3 1.6 1.0	Vdc
Base - Emitter Saturation Voltage (Note 4) (I <sub>C</sub> = 150 mAdc, I <sub>B</sub> = 15 mAdc)  (I <sub>C</sub> = 500 mAdc, I <sub>B</sub> = 50 mAdc)	MMBT2222 MMBT2222A MMBT2222 MMBT2222A V <sub>BE(sat)</sub>	- 0.6 - -	1.3 1.2 2.6 2.0	Vdc
<b>SMALL-SIGNAL CHARACTERISTICS</b>				
Current - Gain - Bandwidth Product (Note 5) (I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 20 Vdc, f = 100 MHz)	MMBT2222 MMBT2222A f <sub>T</sub>	250 300	- -	MHz
Output Capacitance (V <sub>CB</sub> = 10 Vdc, I <sub>E</sub> = 0, f = 1.0 MHz)	C <sub>obo</sub>	-	8.0	pF
Input Capacitance (V <sub>EB</sub> = 0.5 Vdc, I <sub>C</sub> = 0, f = 1.0 MHz)	C <sub>ibo</sub>	- -	30 25	pF
Input Impedance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	MMBT2222A MMBT2222A h <sub>ie</sub>	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback Ratio (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	MMBT2222A MMBT2222A h <sub>re</sub>	- -	8.0 4.0	X 10 <sup>-4</sup>
Small - Signal Current Gain (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	MMBT2222A MMBT2222A h <sub>fe</sub>	50 75	300 375	-
Output Admittance (I <sub>C</sub> = 1.0 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz) (I <sub>C</sub> = 10 mAdc, V <sub>CE</sub> = 10 Vdc, f = 1.0 kHz)	MMBT2222A MMBT2222A h <sub>oe</sub>	5.0 25	35 200	μmhos

# MMBT2222LT1, MMBT2222ALT1

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
<b>SMALL-SIGNAL CHARACTERISTICS</b>				
Collector Base Time Constant ( $I_E = 20\text{ mAdc}$ , $V_{CB} = 20\text{ Vdc}$ , $f = 31.8\text{ MHz}$ )	MMBT2222A		150	ps
Noise Figure ( $I_C = 100\text{ }\mu\text{Adc}$ , $V_{CE} = 10\text{ Vdc}$ , $R_S = 1.0\text{ k}\Omega$ , $f = 1.0\text{ kHz}$ )	MMBT2222A		4.0	dB

## SWITCHING CHARACTERISTICS (MMBT2222A only)

Delay Time	$(V_{CC} = 30\text{ Vdc}$ , $V_{BE(\text{off})} = -0.5\text{ Vdc}$ , $I_C = 150\text{ mAdc}$ , $I_{B1} = 15\text{ mAdc}$ )	$t_d$	-	10	ns
Rise Time		$t_r$	-	25	
Storage Time	$(V_{CC} = 30\text{ Vdc}$ , $I_C = 150\text{ mAdc}$ , $I_{B1} = I_{B2} = 15\text{ mAdc}$ )	$t_s$	-	225	ns
Fall Time		$t_f$	-	60	

- Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .
- $f_T$  is defined as the frequency at which  $|h_{fe}|$  extrapolates to unity.

## SWITCHING TIME EQUIVALENT TEST CIRCUITS

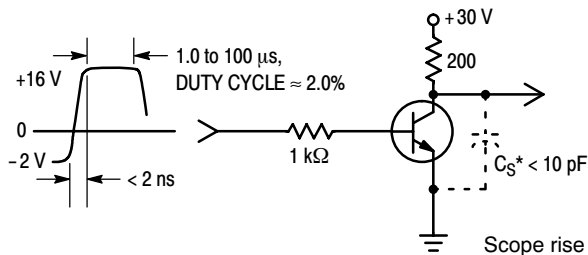


Figure 1. Turn-On Time

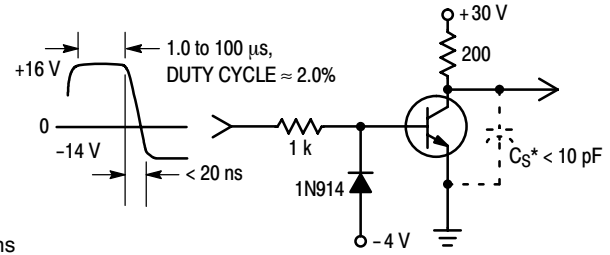


Figure 2. Turn-Off Time

Scope rise time  $< 4\text{ ns}$   
\*Total shunt capacitance of test jig, connectors, and oscilloscope.

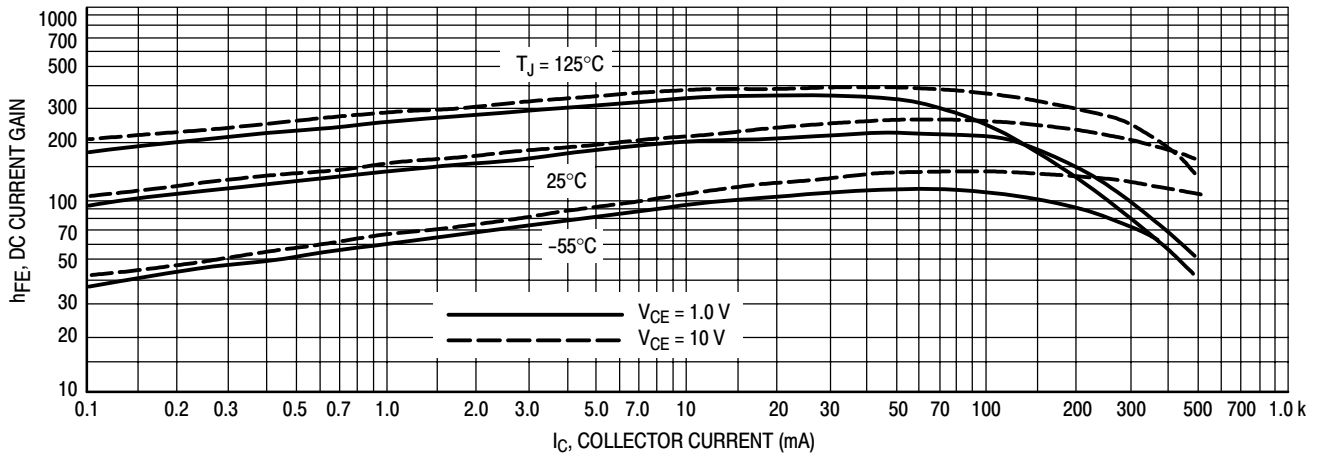


Figure 3. DC Current Gain

# MMBT2222LT1, MMBT2222ALT1

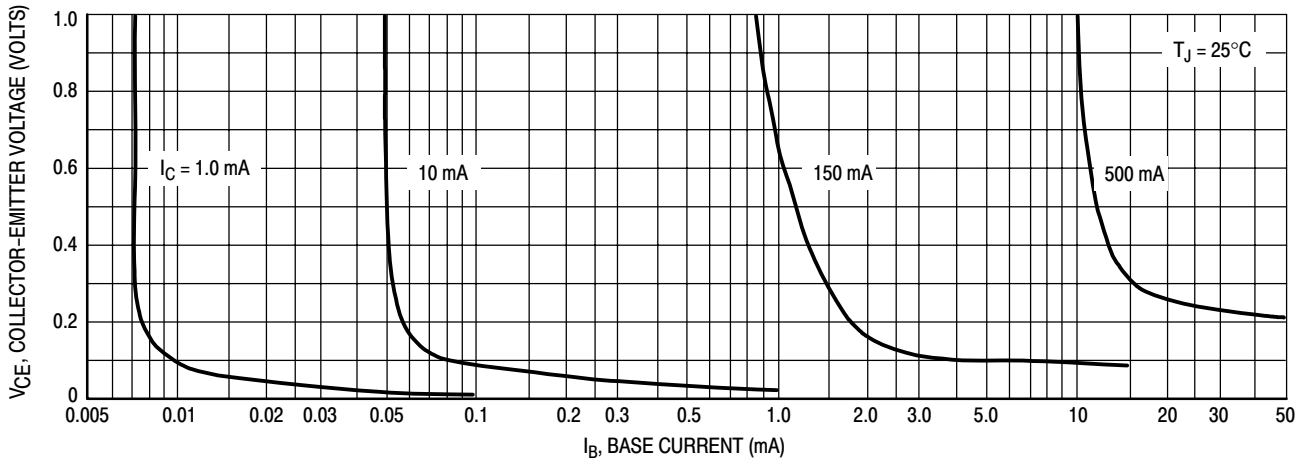


Figure 4. Collector Saturation Region

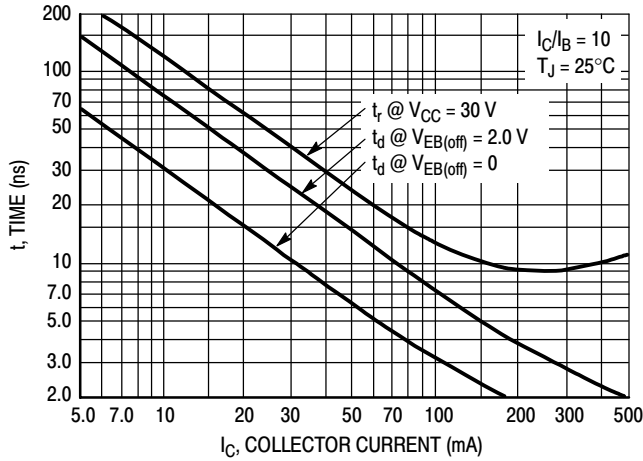


Figure 5. Turn-On Time

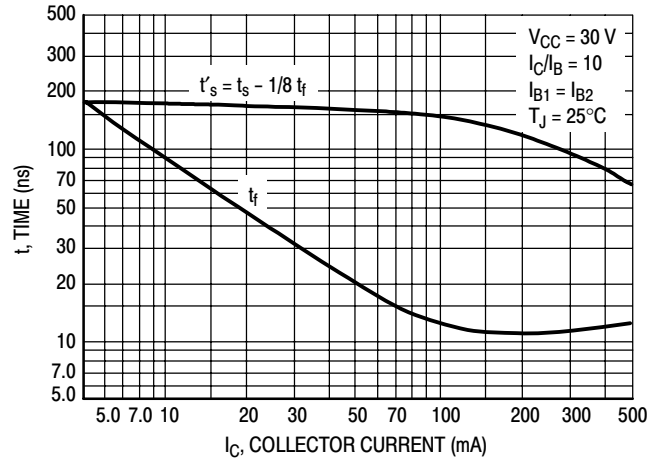


Figure 6. Turn-Off Time

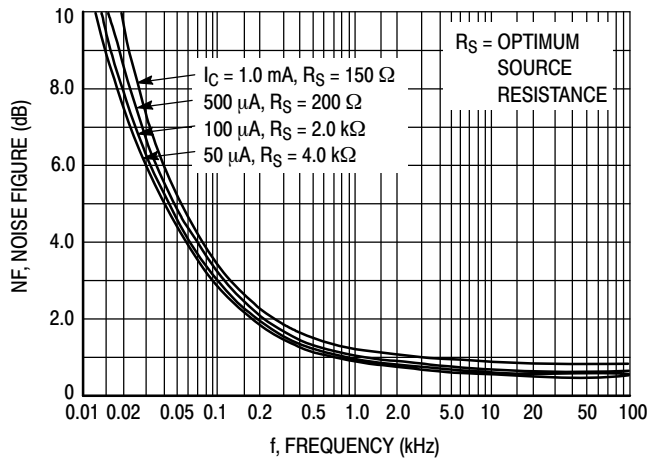


Figure 7. Frequency Effects

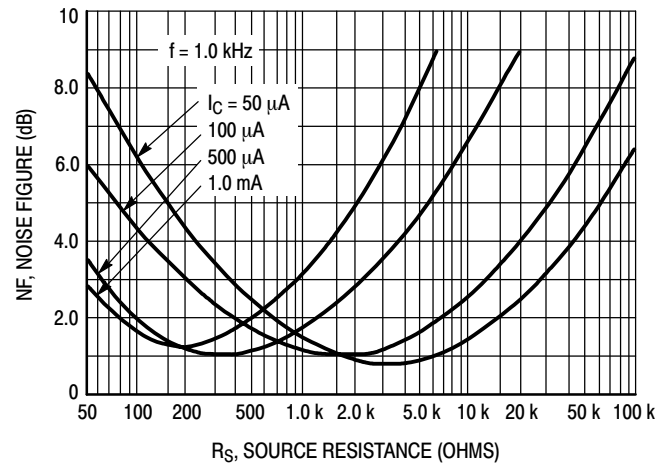


Figure 8. Source Resistance Effects

# MMBT2222LT1, MMBT2222ALT1

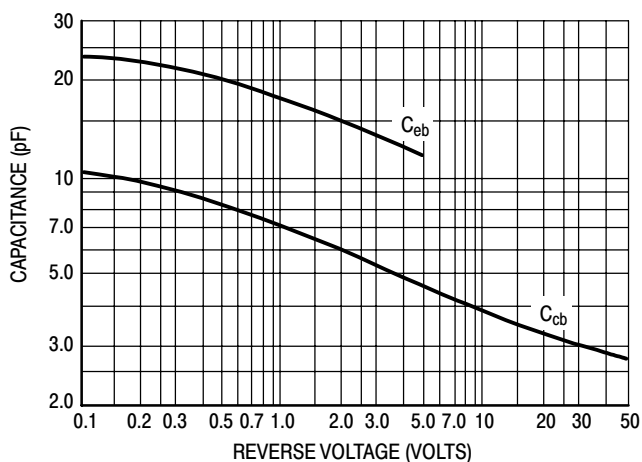


Figure 9. Capacitances

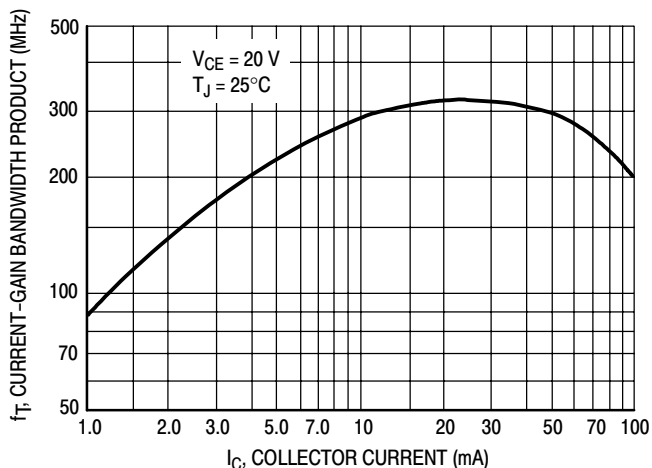


Figure 10. Current-Gain Bandwidth Product

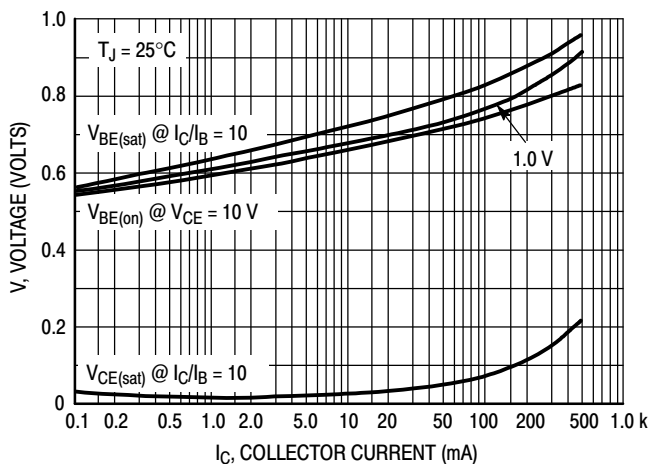


Figure 11. "On" Voltages

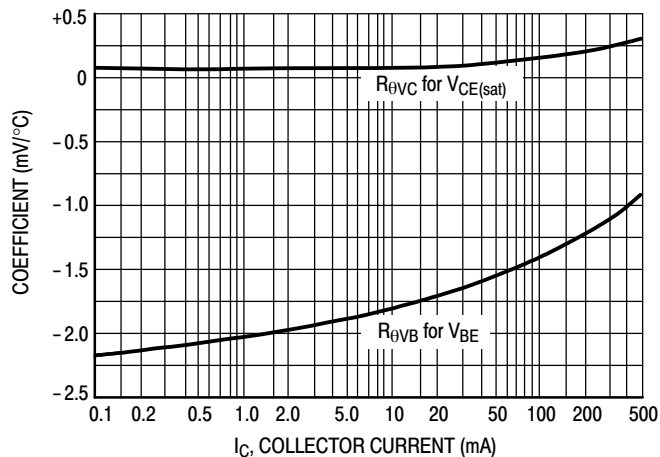


Figure 12. Temperature Coefficients

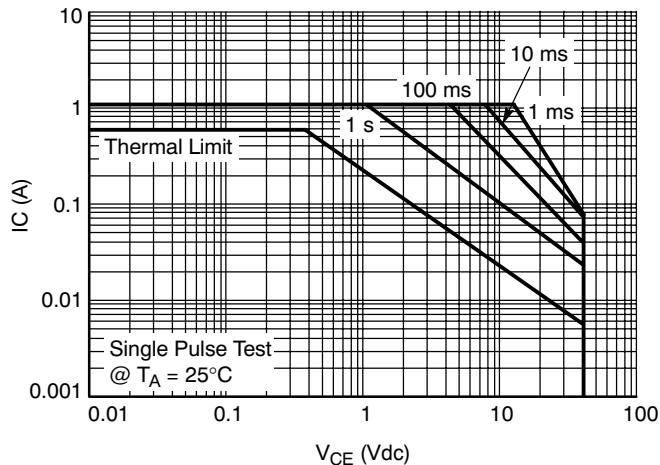


Figure 13. Safe Operating Area

## MMBT2222LT1, MMBT2222ALT1

### ORDERING INFORMATION

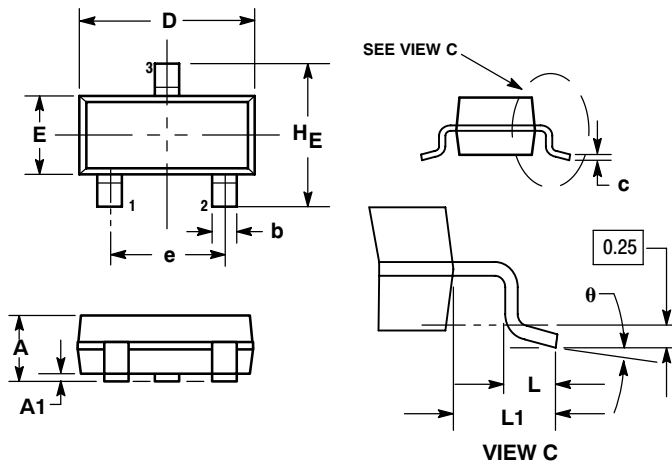
Device	Specific Marking Code	Package	Shipping†
MMBT2222LT1	M1B	SOT-23	3000 / Tape & Reel
MMBT2222LT1G	M1B	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBT2222ALT1	1P	SOT-23	3000 / Tape & Reel
MMBT2222ALT1G	1P	SOT-23 (Pb-Free)	3000 / Tape & Reel
MMBT2222LT3	M1B	SOT-23	10,000 / Tape & Reel
MMBT2222LT3G	M1B	SOT-23 (Pb-Free)	10,000 / Tape & Reel
MMBT2222ALT3	1P	SOT-23	10,000 / Tape & Reel
MMBT2222ALT3G	1P	SOT-23 (Pb-Free)	10,000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MMBT2222LT1, MMBT2222ALT1

## PACKAGE DIMENSIONS

SOT-23 (TO-236)  
CASE 318-08  
ISSUE AN



NOTES:

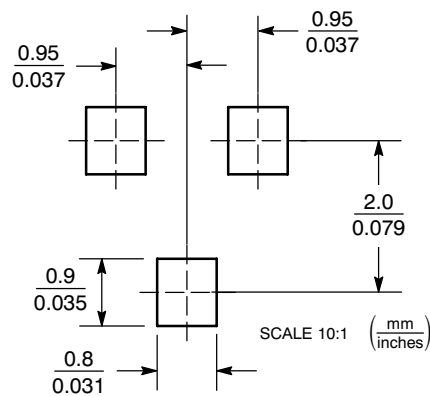
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
c	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
e	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

STYLE 6:

1. BASE
2. EMITTER
3. COLLECTOR

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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